# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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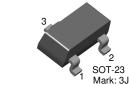
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# **NPN General Purpose Amplifier**

- This device is designed as a general purpose amplifier and switch.
- The useful dynamic range extends to 100mA as a switch and to 100MHz as an amplifier.



TO-92 1. Emitter 2. Base 3. Collector

1. Base 2. Emitter 3. Collector

MPS6515/MMBT6515

## Absolute Maximum Ratings\* T<sub>C</sub>=25°C unless otherwise noted

Symbol	Para	ameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage		25	V
V <sub>CBO</sub>	Collector-Base Voltage		40	V
V <sub>EBO</sub>	Emitter-Base Voltage		4.0	V
С	Collector current	- Continuous	200	mA
TJ, T <sub>sta</sub>	Junction and Storage Temperature		-55 ~ +150	°C

#### NOTES:

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

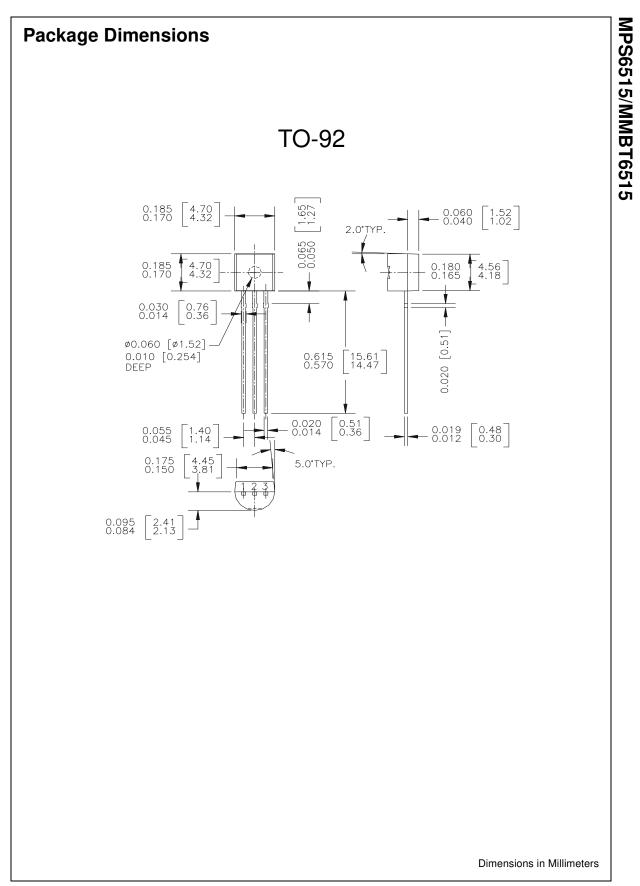
#### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charact	eristics	•	•		
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 0.5 {\rm mA}, I_{\rm B} = 0$	25		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$	40		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm C} = 0$	4.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CE} = 30V, I_E = 0$		50	nA
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 30V, I_E = 0, T = 60^{\circ}C$		1.0	μA
On Charact	eristics *				
h <sub>FE</sub>	DC Current Gain	$I_{C} = 2.0 \text{mA}, V_{CE} = 10 \text{V}$ $I_{C} = 100 \text{mA}, V_{CE} = 10 \text{V}$	250 150	500	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 50mA, I <sub>B</sub> = 5.0mA		0.5	V
Small Signa	al Characteristics				
Cobo	Output Capacitance	V <sub>CB</sub> = 10V, I <sub>F</sub> = 0, f = 100kHz		3.5	pF

Pulse Test: Pulse Width  $\leq 300 \mu s, \, Duty \, Cycle \leq 2.0\%$ 

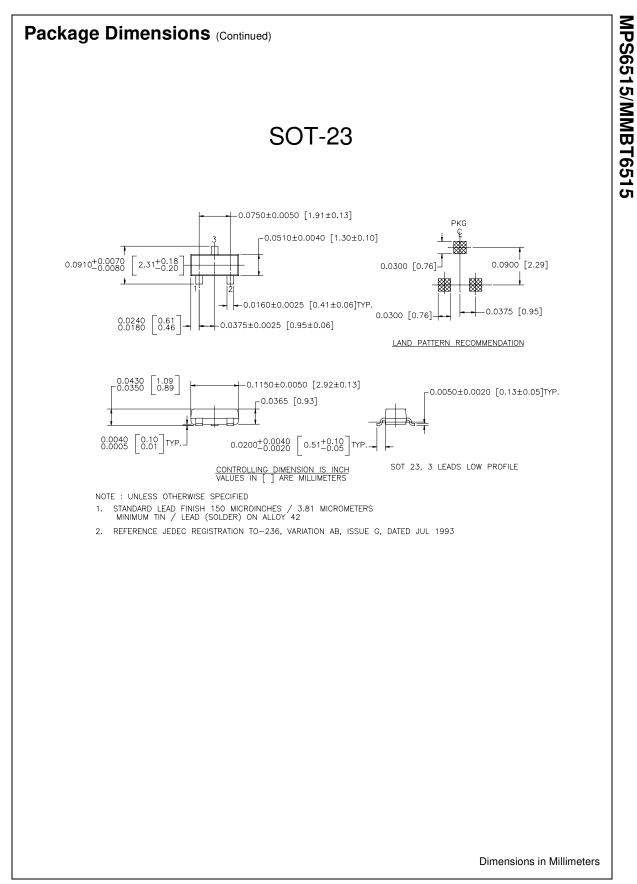
### Thermal Characteristics TA=25°C unless otherwise noted

Symbol	Devenuetov	M	Max.	
	Parameter	MPS6515	*MMBT6515	Units
PD	Total Device Dissipation	625	350	mW
2	Derate above 25°C	5.0	2.8	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3		°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	357	°C/W



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### **PRODUCT STATUS DEFINITIONS**

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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